

BT00100-Delta 100MHz-600MHz 100W

 Scientific and Industrial Applications



The BT-Delta series is a range of class AB RF power amplifiers covering the 100MHz to 600MHz frequency range.

- Rugged, solid-state design high reliability
- Extremely high phase and amplitude stability
- Very fast pulse rise/fall times
- High linearity
- Very low interpulse noise
- Competitively priced

RF Specifications

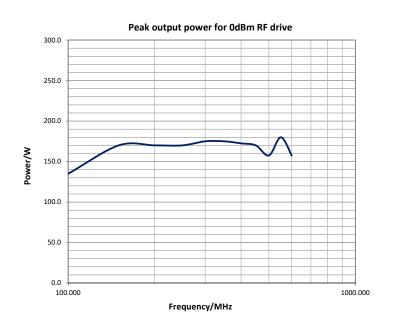
RF Specifications			
Туре	Class AB MOSFET		
Rated Power	100W minimum PEP for input power of 0dBm		
P1dB	80W minimum Minimum output power at P1dB compression		
Gain	50dB minimum		
Frequency	100MHz-600MHz		
Gain flatness	±2dB maximum (measured at 1/10th rated output power)		
Max. duty cycle	20% Maximum GATE duty cycle		
Max. pulse width	300ms Maximum GATE pulse width		
Rated power in CW mode	10W CW operation is automatically available at output power level less than approx. 10% of full rated power		
Pulse droop	0.5dB maximum Measured at max. pulse width at P1dB level		
Pulse rise and fall times	Risetime: 200ns typical Falltime: 100ns typical using a pre-gated RF input signal		
Gate rise and fall times	Risetime: 300ns typical Falltime: 150ns typical		
Gate delay	Rising edge: 1µs typical Falling edge: 500ns typical Rising edge measured from rising edge of GATE pulse to 90% RF output voltage. Falling edge measured from falling edge of GATE pulse to 10% RF output voltage		
Harmonics	Odd: -16dBc typical, -10dBc max. Even: -30dBc typical, -20dBc max. Measured at 1dB below rated output power		
Spurious	<-70dBc maximum		
Output noise (blanked)	<10dB above thermal (100kHz bandwidth)		
Output sample	-50dB into 50 Ω (forward voltage sample)		
Input/output impedance	50 Ω nominal		
Load VSWR	Tolerates at least 3:1 @ full rated power without shut down		
Gain control range	10dB minimum for 0-5V control voltage Control via parallel interface		
RF Input	OdBm nominal, 10dBm for no damage		
GATE (blanking)	Logic low = Blank, logic high = unblank. CMOS and TTL compatible		

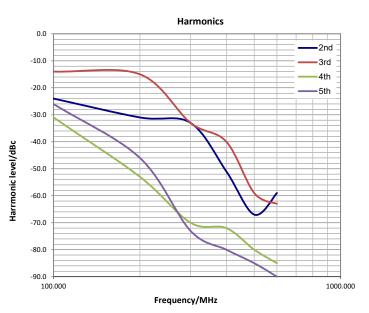
Electrical Specifications

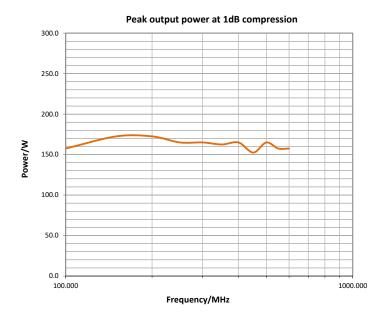
Mains supply voltage	ly voltage 110-240V, 50-60Hz, single phase	
Rated Power	500VA maximum	
Mains inlet	1 x IEC inlet (mains power cord supplied)	

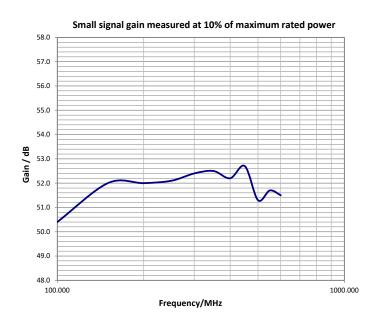


Typical Performance Plots







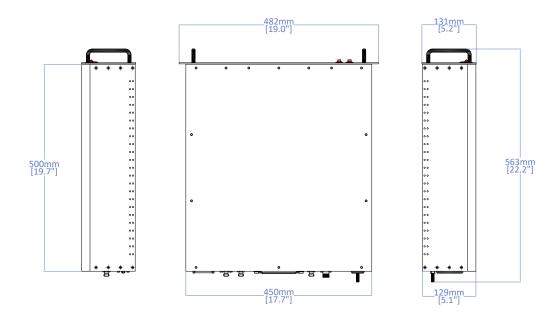


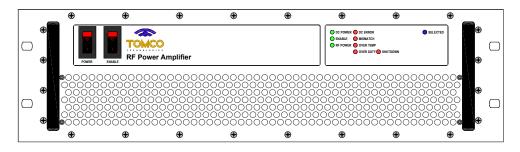
RF Amplifier Data Sheet

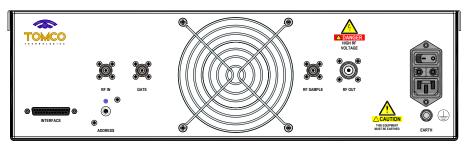


Mechanical Specifications

Connectors	RF IN: BNC female GATE: BNC female RF SAMPLE: BNC female RF OUT: N type female INTERFACE: DB25 female Other connectors types available on request		
Dimensions	Chassis size: 450mmW (17.7"W) x 500mmD (19.7"D) x 129mmH (5.1"H) Total size: 482mmW (19"W) x 563mm (22.2"D) x 131mm (5.2"H) Rack compatibility: 19" 3RU		
Weight	approx. 13kg (28lbs)		
Enclosure classification	IP20		







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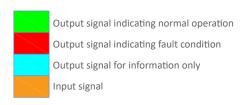


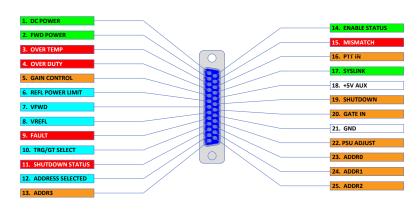
Protection

Load VSWR	Tolerates up to VSWR 3:1 at full rated power without shutdown Self-resetting shutdown protection activates if VSWR limits are exceeded		
Over temperature	Self-resetting shutdown protection activates if thermal limits are exceeded		
Duty cycle	Duty cycle limit is determined from the GATE signal duty cycle. Self-resetting shutdown protection activates if duty cycle limit is exceeded If output power is less than approx. 10% of maximum rated power, duty cycle protection is disabled and auto-CW operation is available		
Pulse width	Pulse width limit is determined from the GATE signal pulse width. Self-resetting shutdown protection activates if pulse width limit is exceeded		

Monitoring and Control

Front panel switches	Power (turns on DC power) Enable (enables RF)			
Front panel LEDs	DC POWER DC ERROR SELECTED ENABLE MISMATCH SHUTDOWN OVER TEMP OVER DUTY			
Parallel interface	25-pin D-connector (pinout available at www.tomcorf.com/pdf/interface.pdf)*			





Environmental

*Some functions may be unavailable on select amplifier models

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General	Intended for use only in controlled, indoor environment. Non-consumer product for industrial and scientific use		
Cooling	Forced air, front to rear		
Operating temperature	+5°C to +40°C		
Storage temperature	-20°C to +60°C		
Humidity	80% for temperature up to 31°C, decreasing linearly to 50% relative humidity at 40°C		
Operating altitude	Up to 2000m		
Pollution degree	2		
Transient voltage compatibilty	Category II, in line with IEC 60364-4-44:2007		
Electromagnetic compatibility	In line with IEC61326-1:2012 ISM equipment, Group 1, Class A For use only in shielded areas. ENC55011 (CISPR 11) limits exceeded by up to 40dB		
Safety	In line with IEC61010-1:2010		
Electromagnetic field strength	In line with ICNIRP Guidelines: 1998, occupational limits		

Change record

Document/Issue number	Originator	Date	Change
DS006686A	JR	31/07/2018	Original
DS006686B	LS	12/01/2021	p.1:H